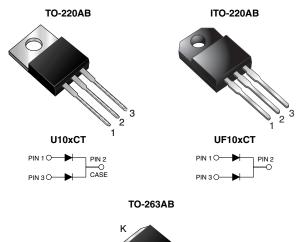
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U10xCT-E3, UF10xCT-E3, UB10xCT-E3

Vishay General Semiconductor

Dual Common Cathode Ultrafast Rectifier





UB10xCT PIN 1 0 K PIN 2 0 HEATSINK

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 5.0 A					
V _{RRM}	100 V to 200 V					
I _{FSM}	55 A					
t _{rr}	25 ns					
VF	0.89 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB					
Diode variations	Dual Common Cathode					

FEATURES

- Power pack
- Oxide planar chip junction
- Ultrafast recovery time
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF max. peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB and TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	U(F,B)10BCT	U(F,B)10CCT	U(F,B)10DCT	UNIT		
Max. repetitive peak reverse voltage		V _{RRM}	100	150	200	V		
Max. average forward rectified current (Fig. 1)	total device	1		A				
	per diode	I _{F(AV)}	5.0					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	55			А		
Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 k Ω (contact mode)		V _C	8			kV		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min per diode		V _{AC}	1500			V		
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150			°C		

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Max. instantaneous forward voltage per diode ⁽¹⁾	$I_{F} = 3.0 \text{ A}$	T _J = 25 °C	- V _F	0.97	-	V	
	I _F = 5.0 A			1.05	1.10		
	I _F = 3.0 A	T _J = 150 °C		0.79	-		
	$I_{F} = 5.0 \text{ A}$			0.89	0.95		
Max. reverse current per diode ⁽²⁾	rated V _R	$T_J = 25 \ ^{\circ}C$	I _R	0.5	5.0	μA	
		$T_J = 100 \ ^{\circ}C$		100	200		
Max. reverse recovery time per diode	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		• t _{rr}	13	20	ns	
	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}, I_{rr} = 0.1 \text{ IRM}$			19.7	25		
Max. stored charge per diode	$I_F = 2 \text{ A}, \text{ dI/dt} = 20 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}, I_{rr} = 0.1 \text{ IRM}$		Q _{rr}	3	9	nC	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	U10XCT	UF10XCT	UB10XCT	UNIT	
Typical thermal resistance per diode	$R_{\theta JA}$	25	25	25	°C/W	
l'ypical thermal resistance per diode	$R_{ ext{ heta}JC}$	5.3	7.5	5.3	0/10	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	U10DCT-E3/4W	1.87	4W	50/tube	Tube		
ITO-220AB	UF10DCT-E3/4W	1.77	4W	50/tube	Tube		
TO-263AB	UB10DCT-E3/4W	1.31	4W	50/tube	Tube		
TO-263AB	UB10DCT-E3/8W	1.31	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

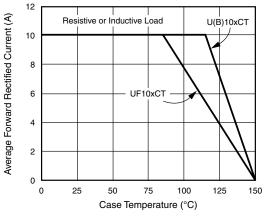


Fig. 1 - Max. Forward Current Derating Curve

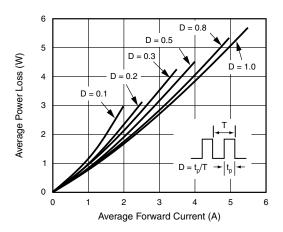


Fig. 2 - Forward Power Loss Characteristics Per Diode

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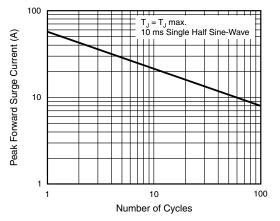


Fig. 3 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

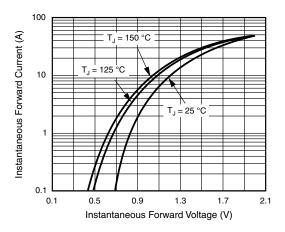


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

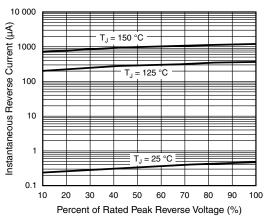


Fig. 5 - Typical Reverse Characteristics Per Diode

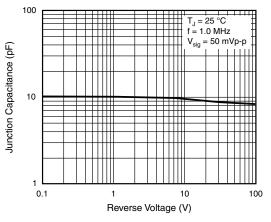


Fig. 6 - Typical Junction Capacitance Per Diode

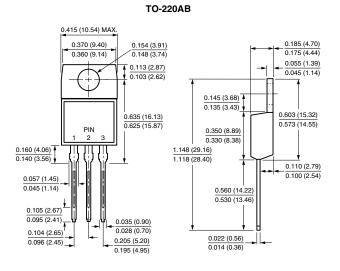
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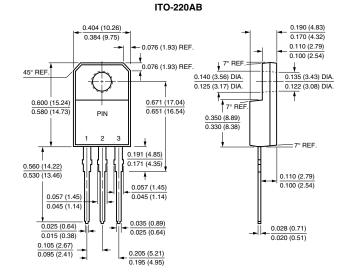


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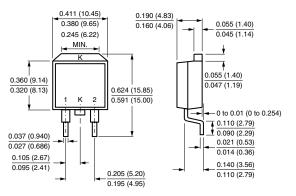
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

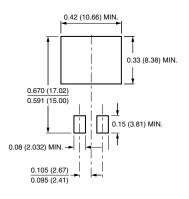




TO-263AB



Mounting Pad Layout





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